

# **Power Supply IC Series for TFT-LCD Panels**

# **5V Input Multi-channel System Power Supply IC**



**BD8179MUV** No.09035EBT04

### Description

The BD8179MUV is a system power supply IC for TFT panels.

A 1-chip IC providing a total of three voltages required for TFT panels, i.e., source voltage, gate high-level, and gate low-level voltage, thus constructing a TFT panel power supply with minimal components required.

### Features

- 1) Step Up DC/DC Converter.
- 2) Incorporates 18V, 3.0A N-channel FET
- 3) Linear-Regulator Controllers for VGON and VGOFF
- 4) 5 channel Operational Amplifiers/±150mA Output Short-Circuit Current 40V / µs Slew Rate
- 5) Switching Frequency: 1200 kHz.
- 6) Gate Shading Function Included.
- 7) Protection Circuits
- 8) Over Current Protection
- 9) Timer Latch Mode Short Current Protection.
- 10) Thermal Shut Down.
- 11) Under Voltage Protection.
- 12) Over Voltage Protection
- 13) VQFN032V5050 Package

### Applications

Liquid crystal TV, PC monitor, and TFT-LCD panel

### ● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limit	Unit
Power Supply Voltage	Vin	7	V
VMAIN Voltage	VMAIN	20	V
SUP Voltage	Vsup	20	V
DRVP Voltage	VDRVP	40	V
DRVN Voltage	Vdrvn	-30	V
SRC Voltage	Vsrc	40	V
CTL Voltage	VCTL	7	V
Junction Temperature	Tjmax	150	°C
Power Dissipation	Pd	4560	mW
Operating Temperature Range	Topr	-40~85	°C
Storage Temperature Range	Tstg	-55~150	°C

<sup>\*</sup> Reduced by 19.52 mW/°C over 25°C, when mounted on a glass epoxy board. (4-layer 74.2 mm  $\times$  74.2 mm  $\times$  1.6 mm).

# Operating Condition

Davamatar	Cymahal	Li	1.1	
Parameter	Symbol Min. Max.		Unit	
Power Supply Voltage	VIN	2.6	5.5	V
VMAIN Voltage	VMAIN	8	18	V
SUP Voltage	Vsup	-	18	V
DRVP Voltage	VDRVP	-	38	V
DRVN Voltage	Vdrvn	-	-20	V
SRC Voltage	Vsrc	-	38	V

●Electrical Characteristics (Unless otherwise specified, VIN = 3.3V; VSUP = 12 V; VGON = 25 V; VGOFF = -6V; Ta = 25°C)

1 DC/DC CONVERTER CONTROLLER BLOCK

1 DC/DC CONVERTER CONTROLLER BLOCK						
Parameter	Symbol	Min.	Limit	Max.	Unit	Conditions
[ ERROR AMPLIFIER BLOCK ]		IVIII I.	Тур.	IVIAX.		
FB Input Bias Current	IFB		0.1			
	VFB	1.221	1.233	1.245	μA V	Buffer, No load
Feed Back Voltage				_		, , , , , , , , , , , , , , , , , , ,
Comp Sink Current	loi	1	5	10	μΑ	VFB=1.5V VCOMP=0.5V
Comp Source Current	loo	-10	-5	-1	μA	VFB=1.0V VCOMP=0.5V
[ LX BLOCK ]	T _					
LX ON-Resistance	Ron	-	200	-	mΩ	
LX Leak Current	lleak	-	0	10	μA	VLX=18V
MAX Duty Cycle	Dмах	-	90	-	%	
LX Current Limit	ILX	2.5	-	-	Α	
[ INTERNAL SOFT START BLO	CK ]					
Soft Start Delay Time	tss	-	3.25	-	ms	
2. GATE-ON LINEAR REGULATION	TOR CONTE	ROLLER				
Parameter	Symbol		Limit		Unit	Conditions
		Min.	Тур.	Max.		
FBP Voltage	VFBP	1.225	1.25	1.275	V	
FBP Input Bias Current	IFBP	-	0.1	-	μA	
DRVP Current Limit	IDRVP	1	5	10	mA	
3. GATE-OFF LINEAR REGULA	ATOR CONT	ROLLER				
Parameter	Symbol		Limit		Unit	Conditions
		Min.	Тур.	Max.		
FBN Voltage	VFBN	0.235	0.25	0.265	V	
FBN Input Bias Current	IFBN	-	0.1	-	μA	
DRVN Current Limit	IDRVN	1	5	10	mA	
4. OPERATIONAL AMPLIFIERS	3					
Parameter	Symbol		Limit		Unit	Conditions
	•	Min.	Тур.	Max.		
Input Offset Voltage	Voff	-	0	-	mV	VPOS1~5 = 6V
Input Range	VRANGE	0		VSUP	V	
DRIVE Current	ldrv	50	-	-	mA	
Slew Rate	SR	-	40	-	V/us	
5. GATE SHADING CONTROLL	ER BLOCK					
Parameter	Symbol		Limit		Unit	Conditions
		Min.	Тур. Мах.		00.14.110.10	
DEL Start Period	tdd	-	15	-	ms	
DEL Source Current	Idls	-8	-5	-2	μΑ	
DEL Threshold Voltage	Vdls	1.2	1.25	1.3	V	
CTL Input Low Voltage	VctII	-	-	VIN x 0.3	V	
, ,					١./	
CTL Input High Voltage	Vchlh	VIN x 0.7	1	-	V	
	Vchlh Ictl	VIN x 0.7	16.5	- 25	μA	VCTL=3.3V
CTL Input High Voltage						VCTL=3.3V

OThis product is not designed for protection against radioactive rays.

●Electrical Characteristics (Unless otherwise specified, VIN = 3.3V; VSUP = 12 V; VGON = 25 V; VGOFF = -6V; Ta = 25°C) 6. WHOLE DEVICE

		l imit			
Symbol	Min		Max	Unit	Conditions
	IVIIII.	Typ.	Wax.		
VREF	1.231	1.25	1.269	V	
1 11111		1	1	-	
Fosc	1020	1200	1380	kHz	
OUT BLOCK	(]	1		,	
Vuvlo	2.25	2.4	2.55	V	
OUT BLOCK	]			·	
Vovp	18	19	20	V	
ION BLOCK	[]				
Tscp	-	150	-	ms	
					_
Vthfb	0.9	1.0	1.1	V	
Vthfbp	0.9	1.0	1.1	V	
Vthfpn	0.4	0.5	0.6	V	
	VREF  FOSC  OUT BLOCK  Vuvlo  DUT BLOCK  Vovp  TON BLOCK  Tscp  Vthfb  Vthfbp	VREF   1.231     Fosc   1020     OUT BLOCK       Vuvlo   2.25     OUT BLOCK       Vovp   18     ION BLOCK       Tscp   -     Vthfb   0.9     Vthfbp   0.9	VREF   1.231   1.25     VREF   1.231   1.25     Voulo   2.25   2.4     Vovp   18   19     Vovp   18   19     ION BLOCK     Vthfb   0.9   1.0     Vthfbp   0.9   1.0	Symbol         Min.         Typ.         Max.           VREF         1.231         1.25         1.269           Fosc         1020         1200         1380           OUT BLOCK ]         Vuvlo         2.25         2.4         2.55           DUT BLOCK ]         Vovp         18         19         20           TON BLOCK ]         Tscp         -         150         -           Vthfb         0.9         1.0         1.1           Vthfbp         0.9         1.0         1.1	Name

OThis product is not designed for protection against radio active rays.

# ● Reference Data (Unless otherwise specified, Ta = 25°C, VIN=5V)

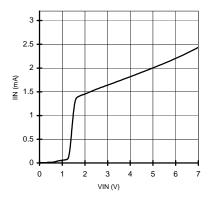


Fig.1 Supply Current (No switching)

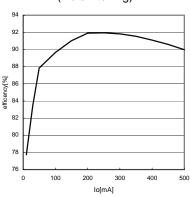


Fig.4 Efficiency vs Output Current (VMAIN)

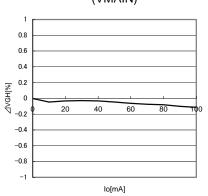


Fig.7 Gate-ON Voltage Load Regulation

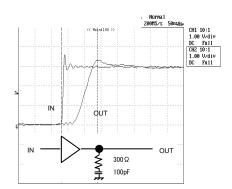


Fig.10 AMP Slew Rate (Rise)

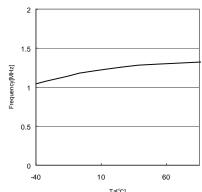


Fig.2 Switching Frequency vs Temperature

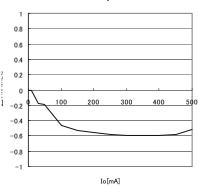


Fig.5 VMAIN Voltage Load Regulation

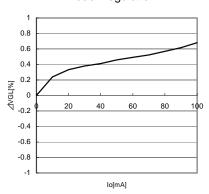


Fig.8 Gate-OFF Voltage Load Regulation

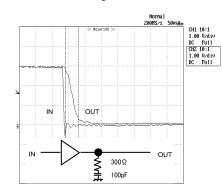


Fig.11 AMP Slew Rate (Fall)

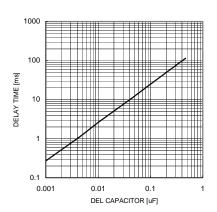


Fig.3 Delay Time vs Capacitor

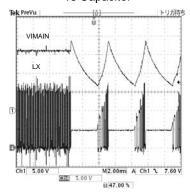


Fig.6 Over Voltage Protect waveform

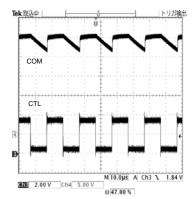


Fig.9 Gate Shading Output waveform

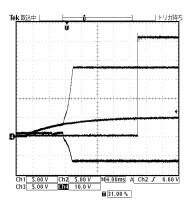
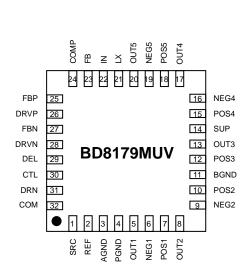
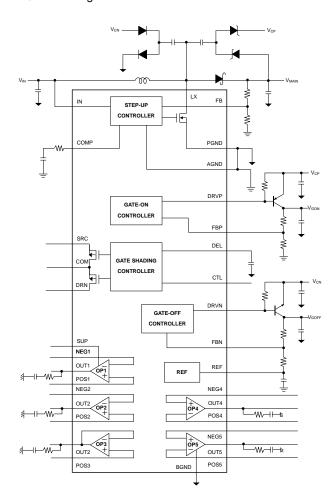


Fig.12 Start Up Sequence waveform

# Pin Assignments Diagram



# ●Block Diagram



Pin Assignments

Pin A	ssignme	ents					
PIN NO.	Pin Name	Function	PIN NO.	Pin Name	Function		
1	SRC	Highside Input for Gate Shading switch	17	OUT4	Operational Amplifier 4 Output		
2	REF	Reference for VGOFF	18	POS5	Operational Amplifier 5 Noninverting Input		
3	AGND	Ground	19	NEG5	Operational Amplifier 5 Inverting Input		
4	PGND	Power Ground	20	OUT5	Operational Amplifier 5 Output		
5	OUT1	Operational Amplifier 1 Output	21	LX	Nch Power MOS FET Drain and Switching Node		
6	NEG1	Operational Amplifier 1 Inverting Input	22	IN	Power Supply voltage Input		
7	POS1	Operational Amplifier 1 Noninverting Input	23	FB	Feedback Input for step up DC/DC		
8	OUT2	Operational Amplifier 2 Output	24	COMP	Error Amplifier Compensation Point for step up DC/DC		
9	NEG2	Operational Amplifier 2 Inverting Input	25	FBP	Feedback Input for Gate-ON Linear-Regulator		
10	POS2	Operational Amplifier 2 Noninverting Input	26	DRVP	Gate-ON Linear-Regulator Base Drive		
11	BGND	Ground	27	FBN	Feedback Input for Gate-OFF Linear-Regulator		
12	POS3	Operational Amplifier 3 Noninverting Input	28	DRVN	Gate-OFF Linear-Regulator Base Drive		
13	OUT3	Operational Amplifier 3 Output	29	DEL	Delay Input for Gate Shading		
14	SUP	Power Supply voltage Input for operational Amplifier	30	CTL	Switch Control Input for Gate Shading		
15	POS4	Operational Amplifier 4 Noninverting Input	31	DRN	Lowside Input for Gate Shading switch		
16	NEG4	Operational Amplifier 4 Inverting Input	32	СОМ	Gate Shading Output		

### ●Block Function

• Step-up Controller

A controller circuit for DC/DC boosting.

The switching duty is controlled so that the feedback voltage FB is set to 1.233 V (typ.).

A soft start operates at the time of starting.

Gate-on Controller

A controller circuit for the positive-side charge pump.

The liner regulator controls so that the feedback voltage FBP will be set to 1.25 V (typ.).

Gate-off Controller

A controller circuit for the negative-side charge pump.

The liner regulator controls so that the feedback voltage FBN will be set to 0.25 V (Typ.).

• Gate Shading Controller

A controller circuit for MOS FET Switch

The COM switching synchronize with CTL input.

Start-up Controller

A control circuit for the starting sequence.

Controls to start in order of VCC →VMAIN →VGOFF/VGON→VCOM

• RFF

A block that generates internal reference voltage. 1.25V (Typ.) is output.

TSD/UVLO/OVP

Thermal shutdown/Under-voltage lockout protection/circuit blocks.

The thermal shutdown circuit is shut down at an IC internal temperature of 175°C and reactivate at 160°C.

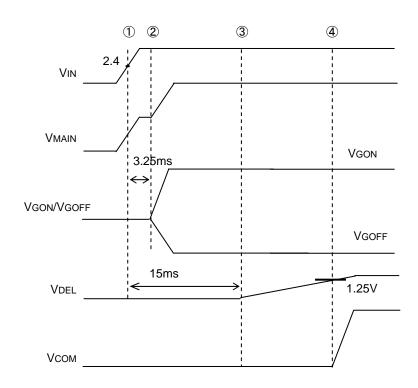
The under-voltage lockout protection circuit shuts down the IC when the VIN is 2.4 V (typ.) or below.

The over-voltage lockout protection circuit shuts down the IC when the SUP is 19.0 V (typ.) or over.

• OP1~OP5

Operational amplifier block

### Starting sequence



- **1)UVLO** released when VIN voltage reaches 2.4V
- 2) Step up DCDC converter starts switching, and VGON and VGOFF starts.
- ③VDEL starts.
- **4**Vcoм ON when VDEL reaches 1.25V

BD8179MUV Technical Note

### • Under Voltage Lock Out (UVLO)

The UVLO circuit compares the input voltage at IN with the UVLO threshold (2.4V rising, 2.2V falling, typ) to ensure the input voltage is high enough for reliable operation.

The 200mV (typ) hysteresis prevents supply transients from causing a restart. Once the input voltage exceeds the UVLO rising threshold, startup begins. When the input voltage falls below the UVLO falling threshold, the controller turns off the main step-up regulator, turns off the linear-regulator outputs, and disables the Gate Shading controller.

### ●Thermal Shut Down (TSD)

The TSD prevents excessive power dissipation from overheating the BD8179MUV. When the junction temperature exceeds  $Tj=175^{\circ}C(Typ)$ , a thermal sensor immediately activates. The fault protection, which shuts down all outputs except the reference, allowing the device to cool down. Once the device cools down by approximately  $15^{\circ}C$  reactivate the device.

### Over Voltage Protection (OVP)

The Step up DC/DC converter has OVP circuit.

The OVP circuit compares the input Voltage at SUP with the OVP threshold (19V rising, 18.5V falling, Typ) to protect the step up DC/DC output exceed the absolute maximum voltage. Once the SUP Voltage exceeds the OVP rising threshold, turn off the main Step-up regulator.

Then, the SUP Voltage falls bellow the OVP falling threshold, reactivate the main Step-Up regulator.

### Over Current Protection (OCP)

The Step-Up DC/DC converter, linear-regulator and Operational Amplifier have OCP circuit respectively.

The OCP circuit restricts to load current, when an OCP activated, one's own output only restricted.

However, if the output continue to overload, the device is possible to activate thermal shutdown or short current protection.

### ●Timer Latch Mode Short Current Protection (SCP)

BD8179MUV has SCP circuit feature to prevent the large current flowing when the output is shorted to GND.

This function is monitoring VMAIN, VGON, and VGOFF Voltage and starts the timer when at least one of the outputs operating properly (when the output voltage was lower than expected).

After 150ms (Typ.) of this abnormal state, the device will shutdown the all outputs and latch the state.

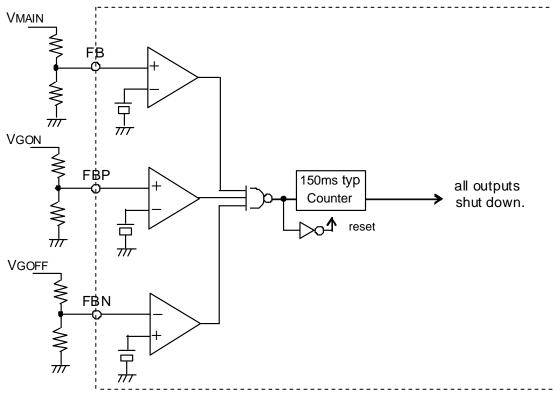


Fig.13 SCP Block Diagram

# Selecting Application Components

### (1) Setting the Output L Constant

The coil to use for output is decided by the rating current ILR and input current maximum value IINMAX of the coil.

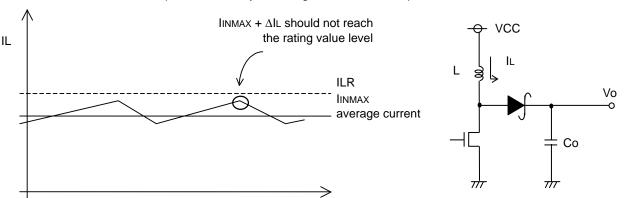


Fig.14 Coil Current Waveform

Fig. 15 Output Application Circuit Diagram

Adjust so that Innmax + $\Delta$ IL does not reach the rating current value ILR. At this time,  $\Delta$ IL can be obtained by the following equation.

$$\Delta IL = \frac{1}{L} \frac{Vcc}{\times} \frac{Vo-Vcc}{Vcc} \times \frac{1}{f}$$
 [A] Here, f is the switching frequency.

Set with sufficient margin because the coil value may have the dispersion of  $\pm 30\%$ . If the coil current exceeds the rating current ILR of the coil, it may damage the IC internal element.

BD8179MUV uses the current mode DC/DC converter control and has the optimized design at the coil value. A coil inductance (L) of  $4.7 \, \mu H$  to  $15 \, \mu H$  is recommended from viewpoints of electric power efficiency, response, and stability.

### (2) Output Capacity Settings

For the capacitor to use for the output, select the capacitor which has the larger value in the ripple voltage VPP allowance value and the drop voltage allowance value at the time of sudden load change. Output ripple voltage is decided by the following equation.

$$\triangle VPP = ILMAX \times RESR + \frac{1}{fCo} \times \frac{Vcc}{Vo} \times (ILMAX - \frac{\triangle IL}{2})$$
 [V] Here, f is the switching frequency.

Perform setting so that the voltage is within the allowable ripple voltage range. For the drop voltage during sudden load change; VDR, please perform the rough calculation by the following equation.

$$VDR = \frac{\Delta I}{Co} \times 10 \text{ us}$$
 [V]

However, 10  $\mu$ s is the rough calculation value of the DC/DC response speed. Please set the capacitance considering the sufficient margin so that these two values are within the standard value range.

### (3) Selecting the Input Capacitor

Since the peak current flows between the input and output at the DC/DC converter, a capacitor is required to install at the input side. For the reason, the low ESR capacitor is recommended as an input capacitor which has the value more than  $10 \, \mu F$  and less than  $100 \, m\Omega$ . If a capacitor out of this range is selected, the excessive ripple voltage is superposed on the input voltage, accordingly it may cause the malfunction of IC.

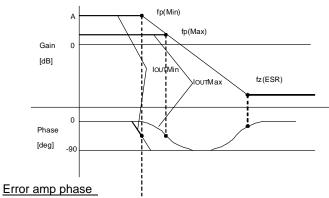
However these conditions may vary according to the load current, input voltage, output voltage, inductance and switching frequency. Be sure to perform the margin check using the actual product.

**Technical Note BD8179MUV** 

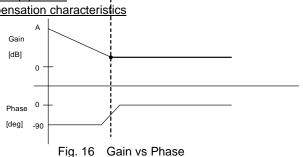
# (4) Setting Rc, Cc of the Phase Compensation Circuit

In the current mode control, since the coil current is controlled, a pole (phase lag) made by the CR filter composed of the output capacitor and load resistor will be created in the low frequency range, and a zero (phase lead) by the output capacitor and ESR of capacitor will be created in the high frequency range. In this case, to cancel the pole of the power amplifier, it is easy to compensate by adding the zero point with Cc and Rc to the output from the error amp as shown in the illustration.

## Open loop gain characteristics



compensation characteristics



$$\mathsf{Fp} = \frac{1}{2 \pi \times \mathsf{Ro} \times \mathsf{Co}} \quad [\mathsf{Hz}]$$

$$fz(ESR) = \frac{1}{2\pi \times ESR \times CO}$$
 [Hz]

Pole at the power amplification stage

When the output current reduces, the load resistance Ro increases and the pole frequency lowers.

$$fp(Min) = \frac{1}{2 \pi \times ROMax \times CO} [Hz] \leftarrow at light load$$

$$fz(Max) = \frac{1}{2 \pi \times ROMin \times CO}$$
 [Hz]—at heavy load

# Zero at the power amplification stage

When the output capacitor is set larger, the pole frequency lowers but the zero frequency will not change. (This is because the capacitor ESR becomes 1/2 when the capacitor becomes 2 times.)

$$fp(Amp.) = \frac{1}{2 \pi \times Rc \times Cc} [Hz]$$

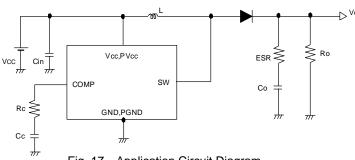


Fig. 17 Application Circuit Diagram

It is possible to realize the stable feedback loop by canceling the pole fp(Min.), which is created by the output capacitor and load resistor, with CR zero compensation of the error amp as shown below.

fz(Amp.) = fp(Min.)

$$\frac{1}{2 \pi \times Rc \times Cc} - \frac{1}{2 \pi \times Romax \times C} [Hz]$$

# (5) Design of the Feedback Resistor Constant

Refer to the following equation to set the feedback resistor. As the setting range,  $10 \text{ k}\Omega$  to  $330 \text{ k}\Omega$  is recommended. If the resistor is set lower than a  $10 \text{ k}\Omega$ , it causes the reduction of power efficiency. If it is set more than  $330 \text{ k}\Omega$ , the offset voltage becomes larger by the input bias current  $0.4 \mu A(\text{Typ.})$  in the internal error amplifier.

$$VMAIN = \frac{R1 + R2}{R2} \times 1.233 \quad [V]$$

$$VO \circ R1$$

$$R2 \Rightarrow FB$$

$$R2 \Rightarrow FB$$

$$R2 \Rightarrow FB$$

$$R2 \Rightarrow FB$$

$$R3 \Rightarrow FB$$

### (6) Positive-side Charge Pump Settings

BD8179MUV incorporates a charge pump controller, thus making it possible to generate stable gate voltage. The output voltage is determined by the following formula. As the setting range,  $10~\text{k}\Omega$  to  $330~\text{k}\Omega$  is recommended. If the resistor is set lower than a  $10\text{k}\Omega$ , it causes the reduction of power efficiency. If it is set more than  $330~\text{k}\Omega$ , the offset voltage becomes larger by the input bias current  $0.4~\text{\mu}A$  (Typ.) in the internal error amp.

$$V_{GON} = \frac{R3 + R4}{R4} \times 1.25 \quad [V]$$

$$1000 \text{ pF to } 4700 \text{ pF}$$

$$R4 = \frac{1.25 \text{ V}}{R4}$$

$$R6 = \frac{1.25 \text{ V}}{R4}$$

In order to prevent output voltage overshooting, add capacitor C3 in parallel with R3. The recommended capacitance is 1000 pF to 4700 pF. If a capacitor outside this range is inserted, the output voltage may oscillate.

By connecting capacitance to the DEL, a rising delay time can be set for the positive-side charge pump.

The delay time is determined by the following formula.

• Delay time of charge pump block t DELAY

t DELAY = ( CDEL 
$$\times$$
 1.25 )/5  $\mu$ A [s]

Where, CDEL is the external capacitance.

### (7) Negative-side Charge Pump Settings

BD8179MUV incorporates a charge pump controller for negative voltage, thus making it possible to generate stable gate voltage. The output voltage is determined by the following formula. As the setting range,  $10 \text{ k}\Omega$  to  $330 \text{ k}\Omega$  is recommended. If the resistor is set lower than a  $10 \text{ k}\Omega$ , it causes the reduction of power efficiency. If it is set more than  $330 \text{ k}\Omega$ , the offset voltage becomes larger by the input bias current  $0.4 \text{ }\mu\text{A}$  (Typ.) in the internal error amp.

$$V_{GOFF} = -\frac{R5}{R6} \times 1.0 + 0.25 \text{ V} \quad [V]$$

$$1000 \text{ pF to } 4700 \text{ pF}$$

$$R6 = -\frac{R5}{R6} \times 1.25 \text{ V}$$

The delay time is internally fixed at 200 us.

In order to prevent output voltage overshooting, insert capacitor C5 in parallel with R5. The recommended capacitance is 1000 pF to 4700 pF. If a capacitor outside this range is inserted, the output voltage may oscillate.

BD8179MUV Technical Note

### Notes for use

### 1) Absolute maximum ratings

Use of the IC in excess of absolute maximum ratings such as the applied voltage or operating temperature range may result in IC damage. Assumptions should not be made regarding the state of the IC (short mode or open mode) when such damage is suffered. A physical safety measure such as a fuse should be implemented when use of the IC in a special mode where the absolute maximum ratings may be exceeded is anticipated.

### 2) GND potential

Ensure a minimum GND pin potential in all operating conditions.

### 3) Setting of heat

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

### 4) Pin short and mistake fitting

Use caution when orienting and positioning the IC for mounting on printed circuit boards. Improper mounting may result in damage to the IC. Shorts between output pins or between output pins and the power supply and GND pins caused by the presence of a foreign object may result in damage to the IC.

### 5) Actions in strong magnetic field

Use caution when using the IC in the presence of a strong magnetic field as doing so may cause the IC to malfunction.

# 6) Testing on application boards

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Ground the IC during assembly steps as an antistatic measure, and use similar caution when transporting or storing the IC. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process.

# 7) Ground wiring patterns

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the application's reference point so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring patterns of any external components.

8) This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P/N junctions are formed at the intersection of these P layers with the N layers of other elements to create a variety of parasitic elements. For example, when the resistors and transistors are connected to the pins as shown in Fig. 18, a parasitic diode or a transistor operates by inversing the pin voltage and GND voltage.

The formation of parasitic elements as a result of the relationships of the potentials of different pins is an inevitable result of the IC's architecture. The operation of parasitic elements can cause interference with circuit operation as well as IC malfunction and damage. For these reasons, it is necessary to use caution so that the IC is not used in a way that will trigger the operation of parasitic elements, such as the application of voltages lower than the GND (P board) voltage to input and output pins.

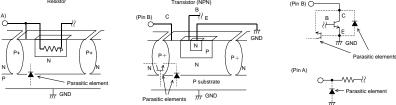


Fig.18 Example of a Simple Monolithic IC Architecture

# 9) Overcurrent protection circuits

An overcurrent protection circuit designed according to the output current is incorporated for the prevention of IC destruction that may result in the event of load shorting. This protection circuit is effective in preventing damage due to sudden and unexpected accidents. However, the IC should not be used in applications characterized by the continuous operation or transitioning of the protection circuits. At the time of thermal designing, keep in mind that the current capability has negative characteristics to temperatures.

### 10) Thermal shutdown circuit

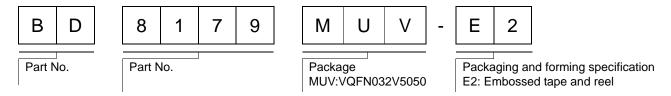
This IC incorporates a built-in thermal shutdown circuit for the protection from thermal destruction. The IC should be used within the specified power dissipation range. However, in the event that the IC continues to be operated in excess of its power dissipation limits, the attendant rise in the chip's temperature Tj will trigger the thermal shutdown circuit to turn off all output power elements. The circuit automatically resets once the chip's temperature Tj drops.

Operation of the thermal shutdown circuit presumes that the IC's absolute maximum ratings have been exceeded. Application designs should never make use of the thermal shutdown circuit.

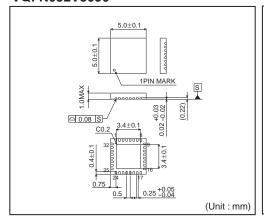
### 11) Testing on application boards

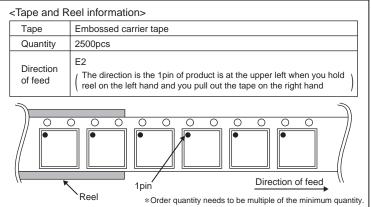
At the time of inspection of the installation boards, when the capacitor is connected to the pin with low impedance, be sure to discharge electricity per process because it may load stresses to the IC. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process. Ground the IC during assembly steps as an antistatic measure, and use similar caution when transporting or storing the IC.

# Ordering part number



# VQFN032V5050





# **Notice**

### **Precaution on using ROHM Products**

Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA	
CLASSⅢ	CLASSⅢ	CLASS II b	CI VCCIII	
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

# **Precautions Regarding Application Examples and External Circuits**

- If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

# **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

### **Precaution for Product Label**

QR code printed on ROHM Products label is for ROHM's internal use only.

### **Precaution for Disposition**

When disposing Products please dispose them properly using an authorized industry waste company.

### **Precaution for Foreign Exchange and Foreign Trade act**

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

### **Precaution Regarding Intellectual Property Rights**

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data. ROHM shall not be in any way responsible or liable for infringement of any intellectual property rights or other damages arising from use of such information or data.:
- 2. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the information contained in this document.

# **Other Precaution**

- 1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
- 2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
- 3. In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
- The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

### **General Precaution**

- 1. Before you use our Products, you are requested to care fully read this document and fully understand its contents. ROHM shall not be in an y way responsible or liable for failure, malfunction or accident arising from the use of a ny ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this docume nt is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sale s representative.
- 3. The information contained in this doc ument is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate an d/or error-free. ROHM shall not be in an y way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.

**Notice – WE** © 2014 ROHM Co., Ltd. All rights reserved. Rev.001



Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

# Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



**«JONHON»** (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«**FORSTAR**» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: http://oceanchips.ru/

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А